TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC7W66FU, TC7W66FK

Dual Bilateral Switch

The TC7W66 is a high speed CMOS Dual Bilateral Switch fabricated with silicon gate CMOS technology.

It consists of four independent high speed switches capable of controlling either digital or analog signals while maintaining the CMOS low power dissipation.

Control input (C) is provided to control the switch.

The switch turns ON while the C input is high, and the switch turns OFF while low.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

Features

- High speed: $t_{pd} = 7$ ns (typ.) at VCC = 5 V
- Low power dissipation: $I_{CC} = 1 \ \mu A \ (max)$ at $Ta = 25^{\circ}C$
- High noise immunity: V_{NIH} = V_{NIL} = 28% V_{CC} (min)
- Low ON resistance: $RON = 50 \Omega$ (typ.) at VCC = 9 V
- High degree of linearity: THD = 0.05% (typ.) at V_{CC} = 5 V

Part No.

Lot No.

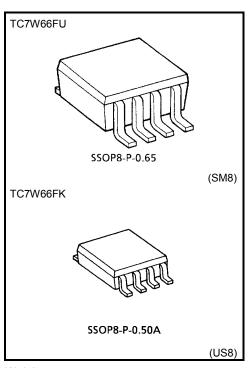
US8

W 66 Part No.

• Pin and function compatible with TC4W66

Marking

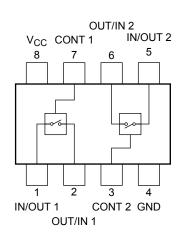
SM8



Weight SSOP8-P-0.65: 0.02 g (typ.) SSOP8-P-0.50A: 0.01 g (typ.)



7 W 6 6



Start of commercial production 1996-02

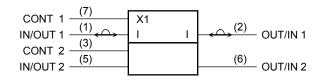
Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit	
Supply voltage range	V _{CC}	-0.5 to 13	V	
DC input voltage	V _{IN}	-0.5 to V_{CC} + 0.5 $$	V	
DC output voltage	V _{OUT}	-0.5 to V_{CC} + 0.5 $$	V	
Input diode current	I _{IK}	±20	mA	
Output diode current	I _{OK}	±20	mA	
DC output current	IOUT	±25	mA	
DC V _{CC} /ground current	ICC	±25	mA	
Dever dissinction	D-	300 (SM8)	mW	
Power dissipation	PD	200 (US8)	IIIVV	
Storage temperature range	T _{stg}	-65 to 150	°C	
Lead temperature (10 s)	ΤL	260	°C	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

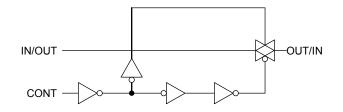
Logic Diagram



Truth Table

Control	Switch Function
Н	ON
L	OFF

Logic Diagram (1/2 TC7W66)



Operating Ranges

Characteristics	Symbol	Rating	Unit
Supply voltage	V _{CC}	2 to 12	V
Control input voltage	V _{IN}	0 to V _{CC}	V
Switch I/O voltage	V _{I/O}	0 to V _{CC}	V
Operating temperature range	T _{opr}	-40 to 85	°C
Input rise and fall time	t _r , t _f	0 to 1000 ($V_{CC} = 2.0 \text{ V}$)	
		0 to 500 ($V_{CC} = 4.5 V$)	ns
		0 to 400 (V _{CC} = 6.0 V)	115
		0 to 250 (V _{CC} = 10.0 V)	

Electrical Characteristics

DC Electrical Characteristics

Characteristics Symbol Te		Symbol Test Condition			Ta = 25°C			Ta = -40 to 85°C		Unit
			V _{CC} (V)		Тур.	Max	Min	Max	••••	
				2.0	1.5	_	_	1.5	_	
	Lligh lovel	N		4.5	3.15	_	_	3.15	_	
	High level	VIHC	_	9.0	6.3	_	_	6.3	_	
Control input				12.0	8.4	_	_	8.4	_	V
voltage				2.0	_	_	0.5	_	0.5	V
	Low level	Maria		4.5	_	_	1.35	_	1.35	
	LOW IEVEI	V _{ILC}	—	9.0		_	2.7	_	2.7	
				12.0	_	_	3.6	_	3.6	
			$V_{IN} = V_{IHC}$ $V_{I/O} = V_{CC}$ to GND	4.5	_	96	170	_	200	
				9.0		55	85	_	100	
			$I_{I/O} \le 1 \text{ mA}$	12.0	-	45	80	_	90	
ON resistance	R _{ON}	$\label{eq:VIN} \begin{array}{l} V_{IN} = V_{IHC} \\ V_{I/O} = V_{CC} \text{ or } GND \\ I_{I/O} \leq 1 \ mA \end{array}$	2.0	_	160	_	_	_	Ω	
			4.5	-	70	100	_	130		
			9.0		50	75	_	95		
			12.0	_	45	70	_	90		
Difference of O	N		V _{IN} = V _{IHC}	4.5		10		_	_	Ω
resistance betw		ΔR_{ON}	$V_{I/O} = V_{CC}$ to GND	9.0		5	-	_	_	
switches			$I_{I/O} \le 1 \text{ mA}$	12.0		5	-	_	_	
Input/output lea current (switch		IOFF		12.0	_	_	±100	_	±1000	nA
Switch input lea current (switch on outp	-	I _{IZ}	$V_{OS} = V_{CC}$ or GND $V_{IN} = V_{IHC}$	12.0	_	_	±100	_	±1000	nA
Control input current IIN		$V_{IN} = V_{CC}$ or GND	12.0		_	±100	_	±1000	nA	
			V _{IN} = V _{CC} or GND	6.0	_	_	1.0	_	10.0	
Quiescent supp	Quiescent supply current			9.0		—	4.0	_	40.0	μΑ
				12.0	-	—	8.0	_	80.0	

AC Electrical Characteristics ($C_L = 50 \text{ pF}$, input $t_r = t_f = 6 \text{ ns}$)

Characteristics	Symbol Test Condition			Ta = 25°C			Ta = -40 to 85°C		Unit
	0,1120		$V_{CC}(V)$	Min	Тур.	Max	Min	Max	U
	φI/O	_	2.0		10	50		65	ns
Phase difference between			4.5		4	10	_	13	
input and output	φι/Ο		9.0	_	3	8		10	
			12.0	_	3	7		9	
			2.0	_	18	100		125	
Output enable time	t _{pZL}	$R_L = 1 \ k\Omega$	4.5	_	8	20		25	ns
	t _{pZH}		9.0	_	6	12		22	
			12.0	_	6	12	_	18	
	t _{pLZ} t _{pHZ}	R _L = 1 kΩ	2.0	_	20	115	_	145	ns MHz
Output disable time			4.5	_	10	23	_	29	
			9.0	_	8	20	_	25	
			12.0	_	8	18	_	22	
	_	$R_L = 1 k\Omega$ $C_L = 15 pF$ $V_{OUT} = 1/2 V_{CC}$	2.0	_	30		_	_	
Maximum control input			4.5	_	30		_	_	
frequency			9.0	_	30		_	_	
			12.0	_	30		_	_	
Control input capacitance	C _{IN}	—		_	5	10	_	10	pF
Switch terminal capacitance	C _{I/O}	—		_	6		—	—	pF
Feed through capacitance	C _{IOS}	—		_	0.5		—	—	pF
Power dissipation capacitance	C _{PD}		(Note)	_	15		_	_	pF

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

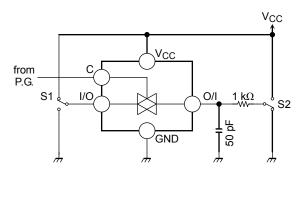
 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/2$

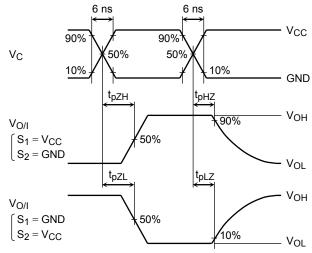
Analog Switch Characteristics (GND = 0 V, Ta = 25°C)

Characteristics	Symbol	Test Condition		Тур.	Unit
Characteriotics	Cymbol		$V_{CC}\left(V\right)$		
Sine wave distortion (T.H.D)		$f_{IN} = 1 \text{ kHz}, V_{IN} = 4.0 \text{ Vp-p} @V_{CC} = 4.5 \text{ V}$	4.5	0.05	0/
	_	$\begin{split} R_L &= 10 \ k\Omega, \ V_{IN} = 8.0 \ V_{p\text{-}p} \ @V_{CC} = 9.0 \ V \\ C_L &= 50 \ pF \end{split}$	9.0	0.04	%
Frequency response (switch ON)	£	Adjust V _{IN} voltage to obtain 0dBm at V _{OS} Increase f _{IN} frequency until dB Meter reads –3dB	4.5	200	
	fmax	$R_L = 50 \Omega$, $C_L = 10 pF$ $f_{IN} = 1 MHz$, sine wave	9.0	200	MHz
Feed Through attenuation (switch OFF)	Ι	V _{IN} is centered at V _{CC} /2 Adjust input for 0dBm	4.5	-60	dB
		$R_L = 600 \ \Omega$, $C_L = 50 \ pF$ $f_{IN} = 1 \ MHz$, sine wave	9.0	-60	uв
Crosstalk (control input to signal output)	_	R_L = 600 Ω , C_L = 50 pF f _{IN} = 1 MHz, square wave (t _r = t _f = 6 ns)	4.5	60	mV
			9.0	100	IIIV
Crosstalk	_	Adjust V_{IN} to obtain 0dBm at input	4.5	-60	10
(between any switches)		$R_L = 600 \Omega$, $C_L = 50 pF$ $f_{IN} = 1 MHz$, sine wave	9.0	-60	dB

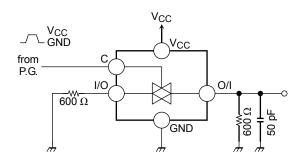
Switching Characteristics Test Circuits

1. t_{pLZ}, t_{pHZ}, t_{pZL}, t_{pZH}

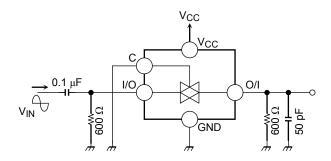




2. Cross Talk (control input-switch output) $f_{IN} = 1 \text{ MHz, } duty = 50\%, \ t_r = t_f = 6 \text{ ns}$

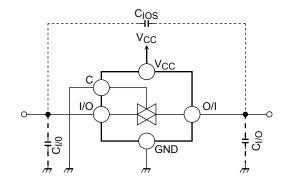


3. Feed Through Attenuation

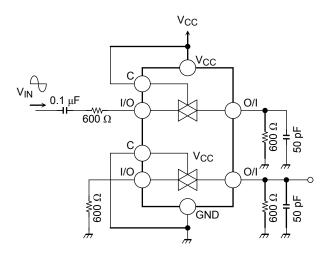


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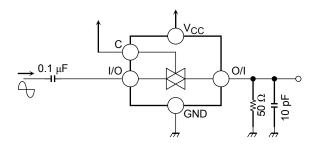
4. C_{IOS}, C_{I/O}



5. Cross Talk (between any two switches)



6. Frequency Response (switch ON)

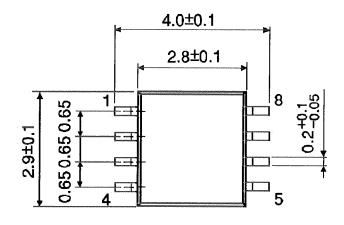


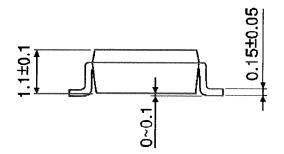
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Package Dimensions

SSOP8-P-0.65

Unit : mm





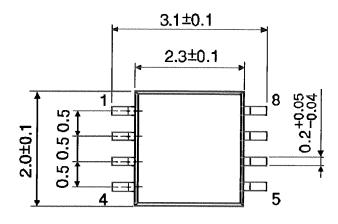
Weight: 0.02 g (typ.)

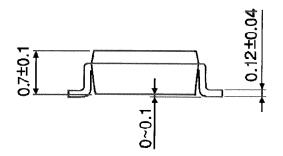
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Package Dimensions

SSOP8-P-0.50A

Unit : mm





Weight: 0.01 g (typ.)

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